

General Description

The MAX4696/MAX4697/MAX4698 low on-resistance (RON), low-voltage analog switches operate from a single +2.0V to +5.5V supply. The MAX4696/MAX4697 are single-pole/single-throw (SPST) analog switches, and the MAX4698 is a single-pole/double-throw (SPDT) analog switch. The MAX4696 is a normally open (NO) switch, and the MAX4697 is a normally closed (NC) switch.

When powered from a 2.7V supply, these devices feature 35Ω (max) R_{ON}, with 2Ω (max) R_{ON} matching and 13Ω (max) flatness. The MAX4696/MAX4697/MAX4698 offer fast switching speeds (ton = 80ns max, toff = 25ns max). The MAX4698 offers a break-before-make function.

The digital logic inputs are 1.8V logic compatible from a +2.7V to +3.3V supply and are TTL/CMOS compatible from a +4.5V to +5.5V supply. The MAX4696/MAX4697/ MAX4698 are packaged in the chip-scale package (UCSP™), significantly reducing the required PC board area. The device occupies only a 1.50mm × 1.02mm area. The 3 × 2 array of solder bumps are spaced with a 0.5mm bump pitch.

Applications

MP3 Players **Battery-Operated Equipment** Relay Replacement Audio and Video Signal Routing Communications Circuits **PCMCIA Cards** Cellular Phones Hard Drives Modems

Features

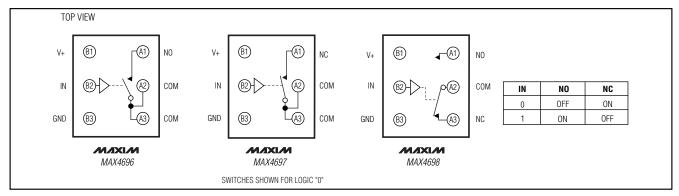
- ♦ 6-Bump, 0.5mm Pitch, UCSP
- ♦ Ron 35 Ω max (+3V Supply) 20 Ω max (+5V Supply)
- ♦ 2Ω max Ron Match Between Channels
- ♦ 13Ω max Ron Flatness Over Signal Range
- **♦** Low Leakage Currents Over Temperature $1nA (max) at T_A = +25^{\circ}C$
- ♦ Fast Switching: toN = 80ns, toFF = 25ns
- ♦ Guaranteed Break-Before-Make (MAX4698)
- ♦ +2.0V to +5.5V Single-Supply Operation
- ♦ Rail-to-Rail[®] Signal Handling
- ♦ Low Crosstalk: -75dB (100kHz)
- ♦ High Off-Isolation: -75dB (100kHz)
- **♦ 1.8V CMOS Logic Compatible**
- ♦ -3dB Bandwidth: >200MHz

Ordering Information

PART	TEMP RANGE	PIN/BUMP- PACKAGE	TOP MARK
MAX4696EBT-T	-40°C to +85°C	6 UCSP	AAL
MAX4697EBT-T	-40°C to +85°C	6 UCSP	AAM
MAX4698EBT-T	-40°C to +85°C	6 UCSP	AAN

Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd. UCSP is a trademark of Maxim Integrated Products, Inc.

Pin Configurations/Functional Diagrams/Truth Table



MIXIM

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

All Voltages Referenced to GND		Continuous Power Dissipa
V+, IN0.3	3V to +6V	3 × 2 UCSP (derate 10.1)
COM, NO, NC (Note 1)0.3V to (V-	+ + 0.3V)	Operating Temperature Ra
Continuous Current COM, NO, NC	±20mA	Storage Temperature Rang
Peak Current COM, NO, NC		Bump Temperature (solde
(pulsed at 1ms, 10% duty cycle)	±40mA	Infrared (15s)
		\\ D\ (00 \

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
3×2 UCSP (derate 10.1mW/°C at +70°C)	808mW
Operating Temperature Range	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Bump Temperature (soldering)	
Infrared (15s)	+220°C
Vapor Phase (60s)	+215°C

Note 1: Signals on NO, NC, and COM exceeding V+ are clamped by an internal diode. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +3V Supply

 $(V+=+2.7V \text{ to } +3.3V, V_{IH}=+1.4V, V_{IL}=0.5V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at +3V and $T_A=+25^{\circ}C.)$ (Notes 2, 8)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}		T _{MIN} to T _{MAX}	0		V+	٧
On Decistores	D	$V+ = +2.7V$, $I_{COM} = 1mA$,	+25°C		30	35	
On-Resistance	Ron	V_{NO} or $V_{NC} = 1.5V$	$T_{\mbox{\scriptsize MIN}}$ to $T_{\mbox{\scriptsize MAX}}$			40	Ω
On-Resistance Match	AD	$V + = +2.7V$, $I_{COM} = 1mA$,	+25°C		1	2	
Between Channels (MAX4698 only) (Note 4)	ΔR _{ON}	V_{NO} or $V_{NC} = 1.5V$	T _{MIN} to T _{MAX}			3	Ω
On-Resistance Flatness	D=, +=(0),	$V+ = +2.7V$, $I_{COM} = 1mA$,	+25°C		10	13	Ω
(Note 5)	R _{FLAT} (ON)	V_{NO} or $V_{NC} = 1V$, 1.5V, 2V	T _{MIN} to T _{MAX}			15	
NO, NC Off-Leakage	I _{NO(OFF)} ,	$V+ = +3.6V$; $V_{COM} = 0.3V$,	+25°C	-0.5	±0.01	0.5	nA
Current (Note 3)	INC(OFF)	$3.3V$; V_{NO} or $V_{NC} = 3.3V$, $0.3V$	$T_{\mbox{\scriptsize MIN}}$ to $T_{\mbox{\scriptsize MAX}}$	-1		1	HA
COM Off-Leakage Current	1	$V + = +3.6V$; $V_{COM} = 0.3V$,	+25°C	-0.5	±0.01	0.5	Λ
(Note 3) (MAX4696, MAX4697 only)	ICOM_(OFF)	$3.3V$; V_{NO} or $V_{NC} = 0.3V$, $3.3V$	T _{MIN} to T _{MAX}	-1		1	nA
COM On-Leakage Current (Note 3)		$V + = +3.6V$; $V_{COM} = 0.3V$,	+25°C	-0.5	±0.01	0.5	nA
	ICOM_(ON)	3.3V; V_{NO} or $V_{NC} = 0.3V$, 3.3V, or floating	T _{MIN} to T _{MAX}	-2		2	TIA
DYNAMIC CHARACTERISTICS							
Turn-On Time (Note 3)	4	$V + = +2.7V$; V_{NO} , $V_{NC} = 1.5V$,	+25°C		50	80	
	ton	$R_L = 300\Omega$, $C_L = 35pF$, Figure 1	T _{MIN} to T _{MAX}			110	ns

ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

 $(V+=+2.7V \text{ to } +3.3V, V_{IH}=+1.4V, V_{IL}=0.5V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at +3V and } T_A=+25^{\circ}C.)$ (Notes 2, 8)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
		$V+ = +2.7V$; V_{NO} , $V_{NC} = 1.5V$,	+25°C		20	25	
Turn-Off Time (Note 3)	toff	$R_L = 300\Omega$, $C_L = 35pF$, Figure 1	T _{MIN} to T _{MAX}			40	ns
Break-Before-Make Time	+	$V+ = +3.3V$; V_{NO} , $V_{NC} = 1.5V$,	+25°C		15		20
(MAX4698 only) (Note 3)	t _{BBM}	Figure 2	T _{MIN} to T _{MAX}	2		ns	
Charge Injection	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1.0$ nF, Figure 3	+25°C	8		рС	
On-Channel -3dB Bandwidth	BW	Signal = 0dBm, 50Ω in and out, Figure 4	+25°C	200			MHz
Off-Isolation (Note 6)	V _{ISO}	$f = 100kHz$, $R_L = 50\Omega$, $C_L = 5pF$, Figure 4	+25°C	-75		dB	
Crosstalk (MAX4698 only) (Note 7)	VCT	f = 100kHz, R _L = 50Ω, C _L = 5pF, Figure 4 +25°(-75		dB	
Total Harmonic Distortion	THD	f = 20Hz to 20 kHz, 2 Vp-p, $R_L = 600\Omega$ + 25 °C			0.014		%
NO, NC Off-Capacitance	C _{NO} (OFF), C _{NC} (OFF)	f = 1MHz, Figure 5	+25°C		15		pF
COM Off-Capacitance	C _C OM(OFF)	f = 1MHz, Figure 5	+25°C		15		рF
Switch On-Capacitance	C _(ON)	f = 1MHz, Figure 6	+25°C		30		рF
DIGITAL I/O							
Input Logic High	VIH		T _{MIN} to T _{MAX}	1.4			V
Input Logic Low	V _{IL}		T _{MIN} to T _{MAX}			0.5	V
Input Leakage Current	I _{IN}	$V_{IN} = 0$ or V_{+}	T _{MIN} to T _{MAX}	-1		1	μΑ
POWER SUPPLY							
Power-Supply Range	V+		T _{MIN} to T _{MAX}	2.0		5.5	V
Supply Current	l+	$V+ = +3.3V$, $V_{IN} = 0$ or $V+$	T _{MIN} to T _{MAX}			1	μΑ

ELECTRICAL CHARACTERISTICS—Single +5V Supply

 $(V+=+4.5V \text{ to } +5.5V, V_{IH}=+2.4V, V_{IL}=0.8V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at +5V and $T_A=+25^{\circ}C.)$ (Notes 2, 8)

PARAMETER	SYMBOL	CONDITIONS T _A		MIN	TYP	MAX	UNITS	
ANALOG SWITCH								
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V	
On-Resistance	$V_{+} = +4.5V$, $I_{COM} = 1mA$,	$V+ = +4.5V$, $I_{COM} = 1mA$,	+25°C		15	20		
On-nesistance	Ron	V_{NO} or $V_{NC} = 1V$, 3.5V	V_{NO} or $V_{NC} = 1V$, 3.5V T_{MIN} to T_{MAX}	T _{MIN} to T _{MAX}			25	Ω
On-Resistance Match	4.0	V+ = 4.5V, I _{COM} = 1mA,	+25°C		1	3		
(MAX4698 only) (Note 4)	ΔR _{ON}	V_{NO} or $V_{NC} = 1V$, 3.5V	T _{MIN} to T _{MAX}			4	Ω	

ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

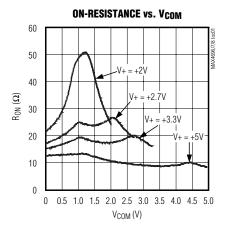
 $(V+ = +4.5V \text{ to } +5.5V, V_{IH} = +2.4V, V_{IL} = 0.8V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at +5V and } T_A = 25^{\circ}\text{C.})$ (Notes 2, 8)

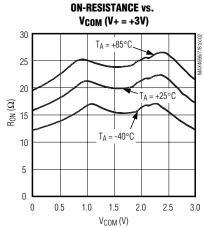
PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
On-Resistance Flatness	D	V+ = +4.5V, I _{COM} = 1mA,	+25°C		3	4	0
(Note 5)	R _{FLAT} (ON)	V_{NO} or $V_{NC} = 1V$, 2.25V, 3.5V	T _{MIN} to T _{MAX}			5	Ω
NO, NC Off-Leakage	INO(OFF),	$V+ = +5.5V; V_{COM} = 1V, 4.5V;$	+25°C	-0.5	±0.01	0.5	nA
Current (Note 3)	INC(OFF)	V_{NO} or $V_{NC} = 4.5V$, 1V	T _{MIN} to T _{MAX}	-1		1	IIA
COM Off-Leakage Current (MAX4696, MAX4697 only)	ICOM (OFF)	$V+ = +5.5V; V_{COM} = 1V, 4.5V;$	+25°C	-0.5	±0.01	0.5	nA
(Note 3)	ICOM_(OFF)	V_{NO} or $V_{NC} = 4.5V$, 1V	T _{MIN} to T _{MAX}	-1		1	IIA
COM On-Leakage Current	loon (on)	$V+ = +5.5V$; $V_{COM} = 1V$, 4.5V; V_{NO} or $V_{NC} = 1V$, 4.5V, or	+25°C	-0.5	±0.01	0.5	nA
(Note 3)	ICOM_(ON)	floating	T _{MIN} to T _{MAX}	-2		2	IIA
T 0 T (N + 0)		$V + = +5.5V$, V_{NO} , $V_{NC} = 3V$,	+25°C		30	40	
Turn-On Time (Note 3)	ton	$R_L = 300\Omega$, $C_L = 35pF$, Figure 1	T _{MIN} to T _{MAX}			50	ns
- 00 01 01 01		$V + = +5.5V$, V_{NO} , $V_{NC} = 3V$,	+25°C		15	-	
Turn-Off Time (Note 3)	toff	$R_L = 300\Omega$, $C_L = 35pF$, Figure 1	T _{MIN} to T _{MAX}			25	ns
Break-Before-Make Time		$V + = +5.5V$, V_{NO} , $V_{NC} = 3V$,	+25°C		9		
(MAX4698 only) (Note 3)	tBBM	$R_L = 300\Omega$, $C_L = 35pF$, Figure 2	T _{MIN} to T _{MAX}	2			ns
DIGITAL I/O							
Input Logic High	VIH			2.4			V
Input Logic Low	VIL					0.8	V
Input Leakage Current	I _{IN}	V _{IN} = 0 or V+		-1		1	μΑ
SUPPLY							
Power-Supply Range	V+			2.0		5.5	V
Supply Current	l+	$V+ = +5.5V$, $V_{IN} = 0$ or $V+$				1	μΑ

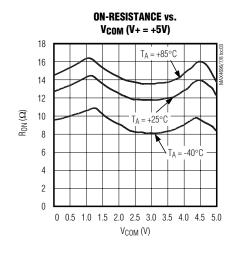
- **Note 2:** The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.
- Note 3: Guaranteed by design.
- **Note 4:** $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$, between switches.
- **Note 5:** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.
- **Note 6:** Off-Isolation = $20log_{10}$ (V_{COM} / V_{NO}), V_{COM} = output, V_{NO} = input to off switch.
- Note 7: Between switches.
- Note 8: UCSP parts are 100% tested at +25°C only, and guaranteed by correlation at the full-rated temperature.

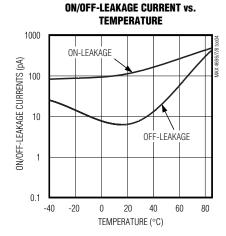
Typical Operating Characteristics

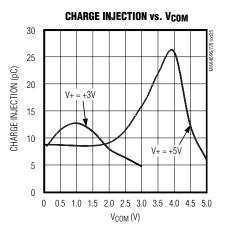
 $(T_A = +25$ °C, unless otherwise noted.)

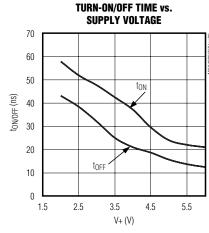


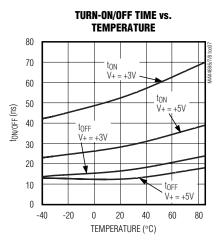


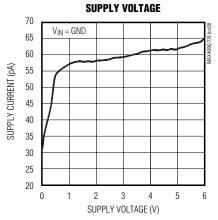




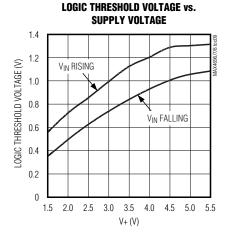






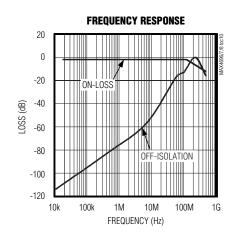


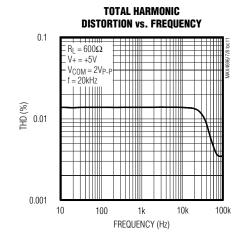
SUPPLY CURRENT vs.



Typical Operating Characteristics (continued)

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$





Pin/Bump Description

	PIN/BUMP			FUNCTION
MAX4696	MAX4697	MAX4698	NAME	FONCTION
B1	B1	B1	V+	Positive Supply Voltage Input
B2	B2	B2	IN	Digital Control Input
В3	В3	В3	GND	Ground
_	A1	А3	NC	Analog Switch, Normally Closed Terminal
A2, A3	A2, A3	A2	COM	Analog Switch, Common Terminal
A1	_	A1	NO	Analog Switch, Normally Open Terminal

Applications Information

Logic Inputs

Where the MAX4696/MAX4697/MAX4698 have a +3.3V supply, IN may be driven low to GND and driven high to 5.5V. Driving IN rail-to-rail minimizes power consumption. Logic inputs accept up to +5.5V regardless of supply voltage.

Analog Signal Levels

Analog signals that range over the entire supply voltage (GND to V+) are passed with very little change in RoN (see *Typical Operating Characteristics*). The switches are bidirectional, so the NO, NC, and COM terminals are both inputs or outputs.

Power-Supply Sequencing and Overvoltage Protection

CAUTION: Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to devices.

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+ before applying analog signals, especially if the analog signal is not current limited. If this sequencing is not possible, and if the analog inputs are not current limited to <20mA, add a small-signal diode (D1) as shown in Figure 6. Adding a protection diode reduces the analog range to a diode drop (about 0.7V) below V+ (for D1). RON increases slightly at low supply voltages. Maximum supply volt-

age (V+) must not exceed +6V. Protection diode D1 also protects against some overvoltage situations. No damage will result on the circuit in Figure 6 if the supply voltage is below the absolute maximum rating and if a fault voltage up to the absolute maximum rating is applied to an analog signal terminal.

UCSP Applications Information

For the latest application details on UCSP construction, dimensions, tape carrier information, printed circuit board techniques, bump-pad layout, and recommended reflow temperature profile as well as the latest information on reliability testing results, go to Maxim's website at www.maxim-ic.com/ucsp for the Application Note "UCSP—A Wafer-Level Chip-Scale Package".

Test Circuits/Timing Diagrams

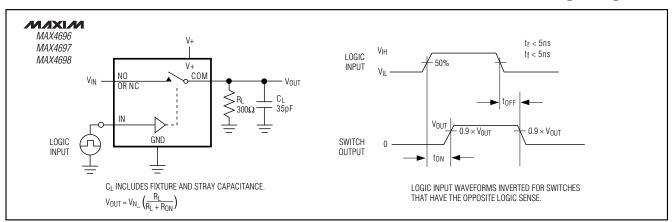


Figure 1. Switching Time

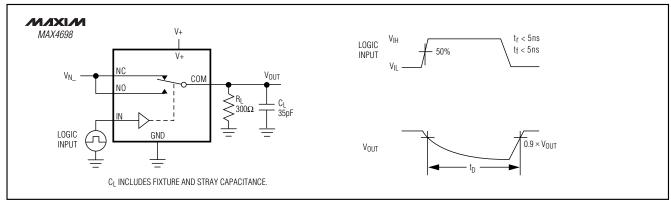


Figure 2. Break-Before-Make Interval (MAX4698 only)

Test Circuits/Timing Diagrams (continued)

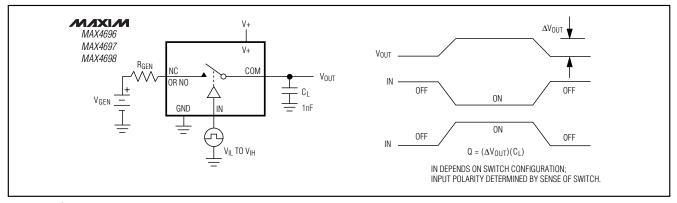


Figure 3. Charge Injection

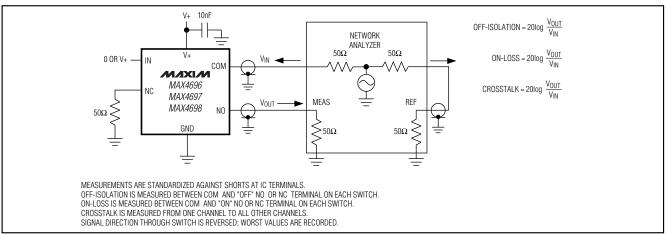


Figure 4. Off-Isolation/On-Channel Bandwidth, Crosstalk

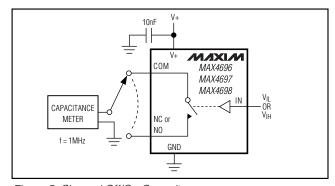


Figure 5. Channel Off/On-Capacitance

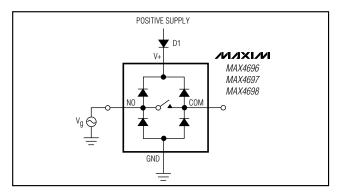


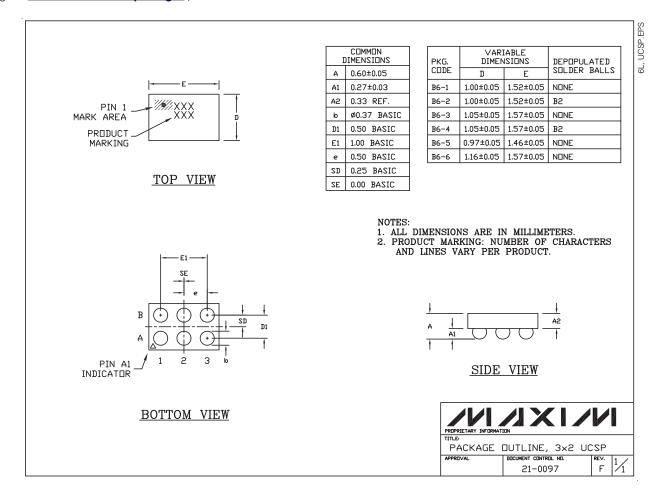
Figure 6. Overvoltage Protection Using External Blocking Diodes

_Chip Information

TRANSISTOR COUNT: 50

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



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